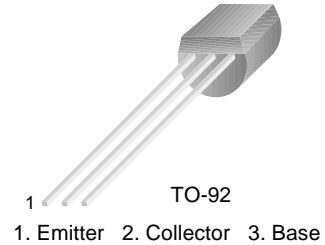


# KSC2001

KSC2001

## General Purpose Applications

- High  $h_{FE}$  and Low  $V_{CE(sat)}$



## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter                   | Value     | Units            |
|-----------|-----------------------------|-----------|------------------|
| $V_{CBO}$ | Collector-Base Voltage      | 30        | V                |
| $V_{CEO}$ | Collector-Emitter Voltage   | 25        | V                |
| $V_{EBO}$ | Emitter-Base Voltage        | 5         | V                |
| $I_C$     | Collector Current           | 700       | mA               |
| $I_B$     | Base Current                | 150       | mA               |
| $P_C$     | Collector Power Dissipation | 600       | mW               |
| $T_J$     | Junction Temperature        | 150       | $^\circ\text{C}$ |
| $T_{STG}$ | Storage Temperature         | -55 ~ 150 | $^\circ\text{C}$ |

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol                 | Parameter                              | Test Condition   | Min.     | Typ.       | Max. | Units |
|------------------------|--|--|----------|------------|------|-------|
| $V_{BE(on)}$           | * Base Emitter On Voltage              | $V_{CE}=6\text{V}, I_C=10\text{mA}$  | 600      | 640        | 700  | mV    |
| $I_{CBO}$              | Collector Cut-off Current              | $V_{CB}=30\text{V}, I_E=0$   |          |            | 100  | nA    |
| $I_{EBO}$              | Emitter Cut-off Current                | $V_{EB}=5\text{V}, I_C=0$  |          |            | 100  | nA    |
| $h_{FE1}$<br>$h_{FE2}$ | * DC Current Gain                      | $V_{CE}=1\text{V}, I_C=100\text{mA}$<br>$V_{CE}=1\text{V}, I_C=700\text{mA}$ | 90<br>50 | 200<br>140 | 400  |       |
| $V_{CE(sat)}$          | * Collector-Emitter Saturation Voltage | $I_C=700\text{mA}, I_B=70\text{mA}$  |          | 0.2        | 0.6  | V     |
| $V_{BE(sat)}$          | * Base-Emitter Saturation Voltage      | $I_C=700\text{mA}, I_B=70\text{mA}$  |          | 0.95       | 1.2  | V     |
| $C_{ob}$               | Output Capacitance                     | $V_{CB}=6\text{V}, I_E=0, f=1\text{MHz}$                                     |          | 13         | 25   | pF    |
| $f_T$                  | Current Gain Bandwidth Product         | $V_{CE}=6\text{V}, I_C=10\text{mA}$  | 50       | 170        |      | MHz   |

\* Pulse test:  $PW \leq 350\mu\text{s}$ , Duty cycle  $\leq 2\%$

## $h_{FE}$ Classification

| Classification | O        | Y         | G         |
|----------------|----------|-----------|-----------|
| $h_{FE1}$      | 90 ~ 180 | 135 ~ 270 | 200 ~ 400 |

# Package Dimensions

## TO-92



Dimensions in Millimeters

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